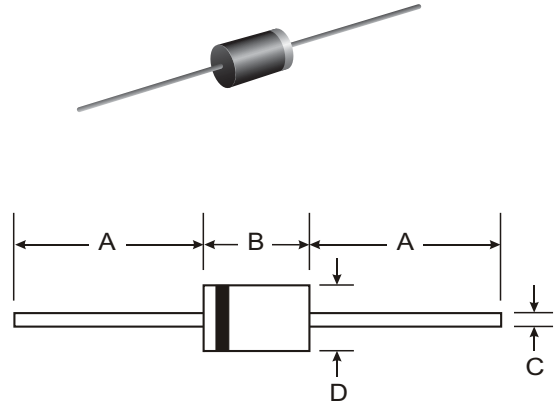


**VOLTAGE RANGE: 20 - 100V**  
**CURRENT: 3.0 A**

### Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



### Mechanical Data

- Case: DO-201AD, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.2 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

DO-201		
Dim	Min	Max
A	25.40	—
B	8.50	9.53
C	0.96	1.06
D	4.80	5.21
All Dimensions in mm		



### Maximum Ratings and Electrical Characteristics @<sub>T<sub>A</sub></sub>=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

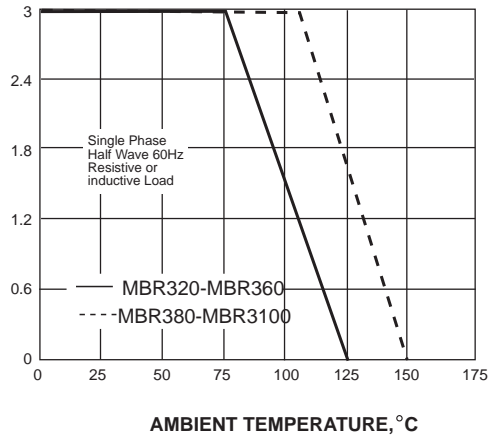
Characteristic	Symbol	MBR320	MBR330	MBR340	MBR350	MBR360	MBR380	MBR3100	Unit	
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>									
Working Peak Reverse Voltage	V <sub>RWM</sub>	20	30	40	50	60	80	100	V	
DC Blocking Voltage	V <sub>R</sub>									
RMS Reverse Voltage	V <sub>R(RMS)</sub>	14	21	28	35	42	56	70	V	
Average Rectified Output Current @ <sub>T<sub>L</sub></sub> = 95°C (Note 1)	I <sub>O</sub>	3.0							A	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	80							A	
Forward Voltage @ <sub>I<sub>F</sub></sub> = 3.0A	V <sub>F</sub>	0.50			0.75		0.85		V	
Peak Reverse Current @ <sub>T<sub>A</sub></sub> = 25°C At Rated DC Blocking Voltage @ <sub>T<sub>A</sub></sub> = 100°C	I <sub>RM</sub>					0.5		20		mA
Typical Junction Capacitance (Note 2)	C <sub>J</sub>					250				pF
Typical Thermal Resistance (Note 1)	R <sub>θJA</sub>					20				°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150							°C	

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.  
 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

## RATINGS AND CHARACTERISTIC CURVES MBR320 THRU MBR3100

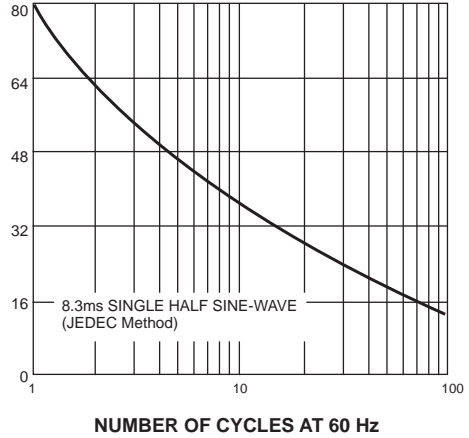
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



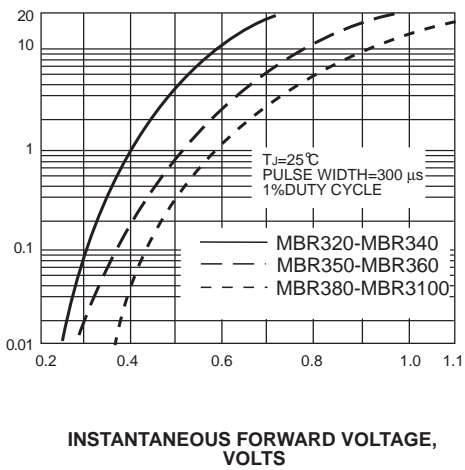
PEAK FORWARD SURGE CURRENT, AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



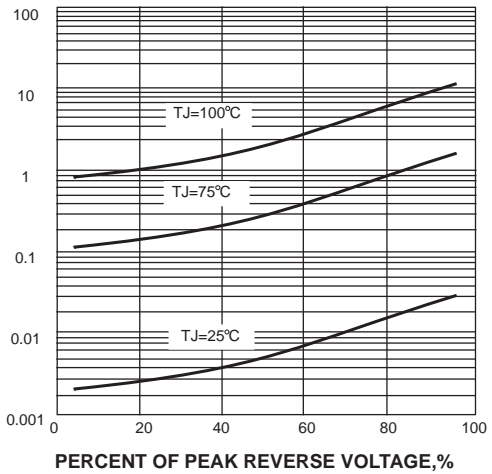
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



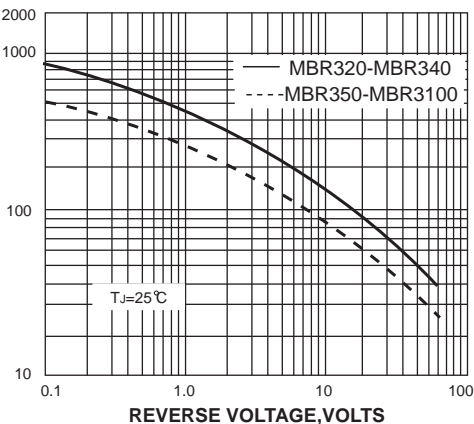
INSTANTANEOUS REVERSE CURRENT, MILLIAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE, °C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

